

GC10DLH THRU GC10MLH

Low VF Rectifier Diode

● FEATURES

- * Halogen-free type
- * Lead free product, compliance to RoHS
- * GPRC (Glass passivated rectifier chip) inside
- * Glass passivated cavity-free junction
- * Lead less chip form, no lead damage
- * Low forward voltage drop
- * Plastic package has Underwriters Laboratory Flammability Classification 94V-0

● APPLICATION

- * General purpose rectification
- * Surge absorption

● MECHANICAL DATA

Case : Packed with FRP substrate and epoxy underfilled

Terminals : Pure Tin plated (Lead-Free), solderable per MIL-STD-750, Method 2026.

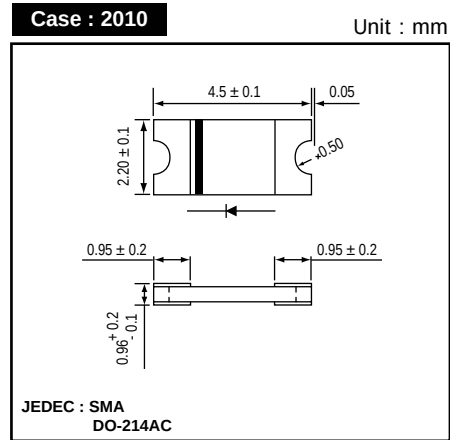
Polarity : Cathode Band, Laser marking

Weight : 0.02 gram

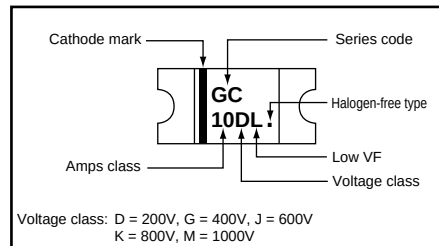
● PACKING

- * 3,000 pieces per 7" (178mm ± 2mm) reel
- * 4 reels per box
- * 6 boxes per carton

● OUTLINE DIMENSIONS



● MARKING



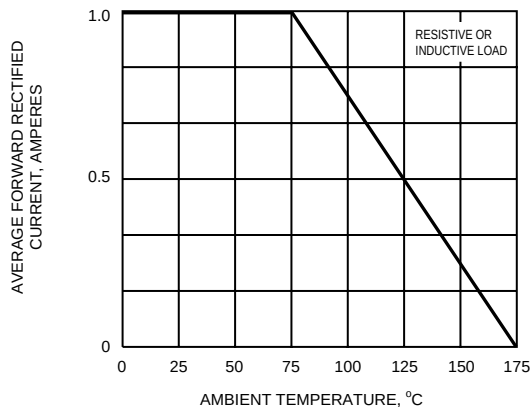
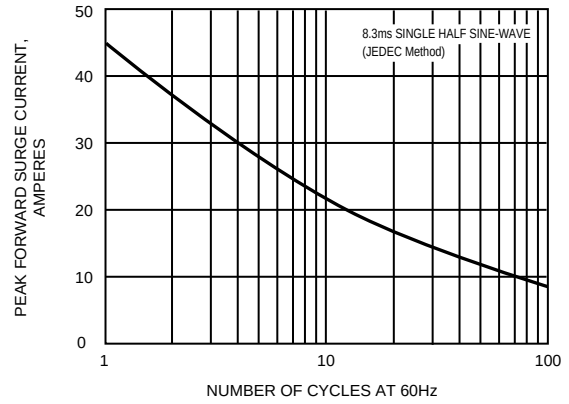
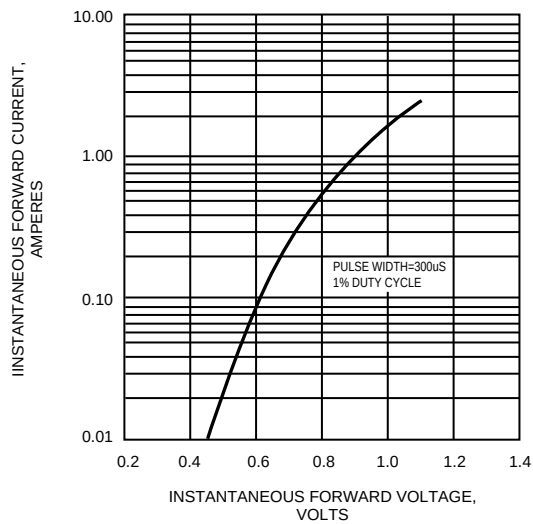
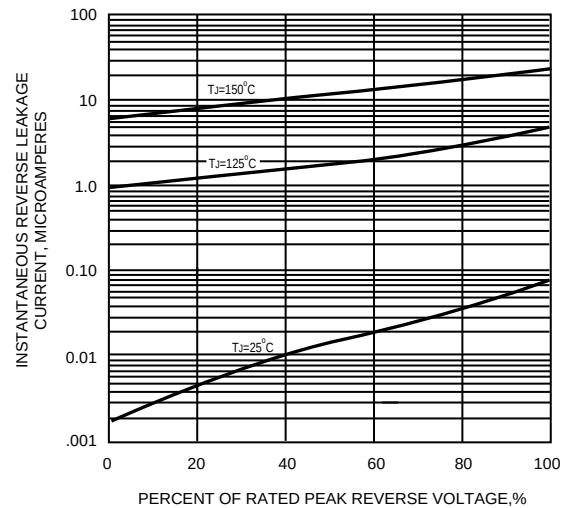
Absolute Maximum Ratings (Ta = 25 °C)

ITEM	Symbol	Rating					Unit
		GC10DLH	GC10GLH	GC10JLH	GC10KLH	GC10MLH	
Repetitive peak reverse voltage	VRRM	200	400	600	800	1000	V
Average forward current	IF(AV)	1.0					A
Peak forward surge current (8.3ms single half sine-wave)	IFSM	45					
Operating junction temperature Range	Tj	-65 to +175					°C
Storage temperature Range	TSTG	-65 to +175					

Electrical characteristics (Ta = 25 °C)

ITEM	Symbol	Conditions	Min.	Typ.	Max.	Unit
Forward voltage	VF	IF = 1.0A	-	0.90	0.92	V
Repetitive peak reverse current	IRRM	VR = Max. VRRM, Ta = 25 °C	-	0.08	5	uA
Junction capacitance	Cj	VR = 4V, f = 1.0 MHz	-	10	-	pF
Thermal resistance	Rth(JA)	Junction to ambient (NOTE)	-	70	-	°C/W
	Rth(JL)	Junction to lead (NOTE)	-	12	-	

NOTES : (1) Thermal resistance from junction to ambient and from junction to lead P.C.B. mounted on 0.2 x 0.2" (5.0 x 5.0mm) copper pad areas.
(2) Preliminary draft.

FIG.1 - FORWARD CURRENT DERATING CURVE

FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

FIG.4 - TYPICAL REVERSE CHARACTERISTICS

FIG.5 - TYPICAL JUNCTION CAPACITANCE
